

**ABSOLUTEMAXIMUMRATINGS**  
(25°C unless otherwise specified)

Storage Temperature	-55°C to +125°C
Operating Temperature	-30°C to +100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

**INPUTDIODE**

Forward Current	50mA
Reverse Voltage	5V
Power Dissipation	70mW

**OUTPUTTRANSISTOR**

Collector-emitter Voltage BV <sub>CEO</sub>	55V
Emitter-collector Voltage BV <sub>ECO</sub>	6V
Collector Current	50mA
Power Dissipation	150mW

**POWERDISSIPATION**

Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

**ELECTRICAL CHARACTERISTICS ( T<sub>A</sub> = 25°C Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V <sub>F</sub> )	1.0	1.15	1.3	V	I <sub>F</sub> = 10mA
	Reverse Current (I <sub>R</sub> )			10	µA	V <sub>R</sub> = 4V
Output	Collector-emitter Breakdown (BV <sub>CEO</sub> ) ( Note 2 )	55			V	I <sub>C</sub> = 0.5mA
	Emitter-collector Breakdown (BV <sub>ECO</sub> )	6			V	I <sub>E</sub> = 100µA
Coupled	Collector-emitter Dark Current (I <sub>CEO</sub> )			100	nA	V <sub>CE</sub> = 24V
	Current Transfer Ratio (CTR) (Note 2) ISP621-1, ISP621-2, ISP621-4	50		600	%	5mA I <sub>F</sub> , 5V V <sub>CE</sub>
	CTR selection available	GB	100	600	%	
		BL	200	600	%	
		GB	30		%	1mA I <sub>F</sub> , 0.4V V <sub>CE</sub>
	Collector-emitter Saturation Voltage V <sub>CE (SAT)</sub>			0.4	V	8mA I <sub>F</sub> , 2.4mA I <sub>C</sub>
	GB			0.4	V	1mA I <sub>F</sub> , 0.2mA I <sub>C</sub>
	Input to Output Isolation Voltage V <sub>ISO</sub>	5300			V <sub>RMS</sub>	See note 1
		7500			V <sub>PK</sub>	See note 1
	Input-output Isolation Resistance R <sub>ISO</sub>	5x10 <sup>10</sup>			Ω	V <sub>IO</sub> = 500V (note 1)
	Rise Time, tr		4		µs	V <sub>CE</sub> = 2V,
	Fall Time, tf		3		µs	I <sub>C</sub> = 2mA, R <sub>L</sub> = 100Ω

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

